# 74AUP2G125

# Low-power dual buffer/line driver; 3-state

Rev. 14 — 21 June 2022

Product data sheet

### 1. General description

The 74AUP2G125 is a dual buffer/line driver with 3-state outputs controlled by the output enable inputs ( $n\overline{OE}$ ). Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- CMOS low power dissipation
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD78B Class II
- · Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- · Input-disable feature allows floating input conditions
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- · ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G125DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G125GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP2G125GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089
74AUP2G125GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	<u>SOT1116</u>
74AUP2G125GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203
74AUP2G125GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	SOT1233-2

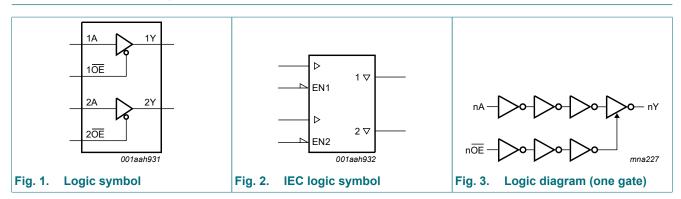
## 4. Marking

Table 2. Marking codes

Type number	Marking code[1]
74AUP2G125DC	p25
74AUP2G125GT	p25
74AUP2G125GF	аМ
74AUP2G125GN	аМ
74AUP2G125GS	аМ
74AUP2G125GX	аМ

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram

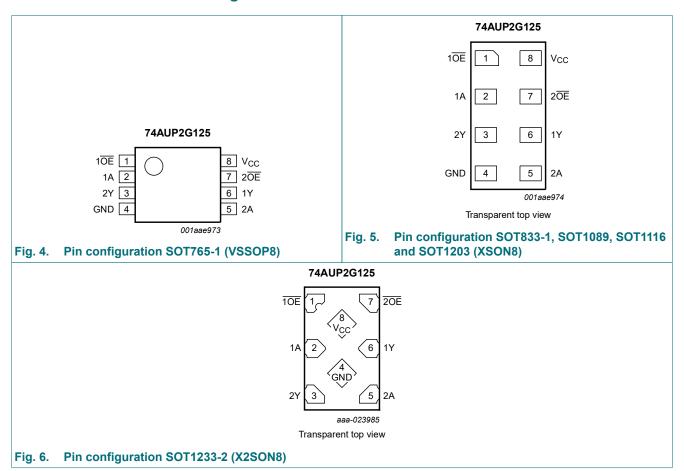


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# 6. Pinning information

### 6.1. Pinning



## 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
10E, 20E	1, 7	output enable input (active LOW)
1A, 2A	2, 5	data input
GND	4	ground (0 V)
1Y, 2Y	6, 3	data output
Vcc	8	supply voltage

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## 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$ 

Input nOE		Output
nŌE	nA	nY
L	L	L
L	Н	Н
Н	X	Z

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+4.6	V
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < 0 V		-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C				
		SOT765-1 (VSSOP8) SOT833-1 (XSON8) SOT1089 (XSON8) SOT1116 (XSON8) SOT1203 (XSON8)	[2] [3] [4] [5] [6]	- - - -	250 250 250 250 250	mW mW mW mW
		SOT1233-2 (X2SON8)	[7]	-	300	mW

- The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- For SOT765-1 (VSSOP8) package: P<sub>tot</sub> derates linearly with 4.9 mW/K above 99 °C.
- For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C. [3]
- [5]
- For SOT1089 (XSON8) package:  $P_{tot}$  derates linearly with 4.0 mW/K above 88 °C. For SOT1116 (XSON8) package:  $P_{tot}$  derates linearly with 4.2 mW/K above 90 °C. For SOT1203 (XSON8) package:  $P_{tot}$  derates linearly with 3.6 mW/K above 81 °C. For SOT1233-2 (X2SON8) package:  $P_{tot}$  derates linearly with 7.7 mW/K above 118 °C.

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# 9. Recommended operating conditions

#### **Table 6. Operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	-	200	ns/V

## 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	5 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μΑ
$\Delta I_{OFF}$	additional power-off leakage current	V <sub>1</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	±0.2 0.5		μΑ	
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
Δl <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; [1] $V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
		$\overline{\text{OE}}$ input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; [1] V <sub>CC</sub> = 3.3 V	-	-	110	μΑ
		all inputs; $V_I$ = GND to 3.6 V; [2] $n\overline{OE}$ = GND; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1	μΑ
Cı	input capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V; } V_I = \text{GND or } V_{CC}$	-	0.8	-	pF
Co	output capacitance	output enabled; V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.4	-	pF
		output disabled; $V_O = GND \text{ or } V_{CC} = 0 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.3	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	0 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		CC = 0.8 V	-	V		
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		$ \begin{array}{c} \text{age} & \bigvee_{\text{CC}} = 0.8 \ \text{V} & 0.70 \times \text{V}_{\text{CC}} & - & - & - \\ \bigvee_{\text{CC}} = 0.9 \ \text{V to } 1.95 \ \text{V} & 0.65 \times \text{V}_{\text{CC}} & - & - \\ \bigvee_{\text{CC}} = 2.3 \ \text{V to } 2.7 \ \text{V} & 1.6 & - & - \\ \bigvee_{\text{CC}} = 3.0 \ \text{V to } 3.6 \ \text{V} & 2.0 & - & - & 0.30 \times \text{V}_{\text{CC}} \\ \bigvee_{\text{CC}} = 0.8 \ \text{V} & - & - & 0.30 \times \text{V}_{\text{CC}} \\ \bigvee_{\text{CC}} = 0.9 \ \text{V to } 1.95 \ \text{V} & - & - & 0.35 \times \text{V}_{\text{CC}} \\ \bigvee_{\text{CC}} = 2.3 \ \text{V to } 2.7 \ \text{V} & - & - & 0.7 \\ \bigvee_{\text{CC}} = 3.0 \ \text{V to } 3.6 \ \text{V} & - & - & 0.9 \\ \bigvee_{\text{I}} = V_{\text{IH}} \text{ or } V_{\text{IL}} \\ &  _{0} = -20 \ \mu\text{A}; \ \text{V}_{\text{CC}} = 0.8 \ \text{V to } 3.6 \ \text{V} & \bigvee_{\text{CC}} - 0.1 & - & - \\  _{0} = -1.1 \ \text{mA}; \ \text{V}_{\text{CC}} = 1.1 \ \text{V} & 0.7 \times \text{V}_{\text{CC}} \\ &  _{0} = -1.9 \ \text{mA}; \ \text{V}_{\text{CC}} = 1.4 \ \text{V} & 1.03 & - & - \\  _{0} = -1.9 \ \text{mA}; \ \text{V}_{\text{CC}} = 1.4 \ \text{V} & 1.03 & - & - \\  _{0} = -2.3 \ \text{mA}; \ \text{V}_{\text{CC}} = 1.65 \ \text{V} & 1.30 & - & - \\  _{0} = -2.3 \ \text{mA}; \ \text{V}_{\text{CC}} = 2.3 \ \text{V} & 1.85 & - & - \\  _{0} = -2.3 \ \text{mA}; \ \text{V}_{\text{CC}} = 2.3 \ \text{V} & 1.85 & - & - \\  _{0} = -2.7 \ \text{mA}; \ \text{V}_{\text{CC}} = 2.3 \ \text{V} & 1.85 & - & - \\  _{0} = -2.7 \ \text{mA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & 2.55 & - & - \\  _{0} = -2.0 \ \text{mA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & 2.55 & - & - \\  _{0} = -2.0 \ \text{mA}; \ \text{V}_{\text{CC}} = 0.8 \ \text{V} \ \text{to } 3.6 \ \text{V} & - & 0.3 \ \text{V}_{\text{CC}} & - & - \\  _{0} = -2.3 \ \text{mA}; \ \text{V}_{\text{CC}} = 2.3 \ \text{V} & - & - & 0.37 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & - & - & 0.37 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & - & - & 0.37 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 0.8 \ \text{V} \ \text{to } 3.6 \ \text{V} & - & - & 0.33 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 1.4 \ \text{V} & - & - & 0.37 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & - & - & 0.33 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & - & - & 0.33 \ \text{I}_{\text{O}} = 1.1 \ \text{MA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & - & - & 0.33 \ \text{I}_{\text{O}} = 1.0 \ \text{MA}; \ \text{V}_{\text{CC}} = 3.0 \ \text{V} & - & - & 0.33 \ \text{I}_{\text{O}} = 1.0 \ $	V			
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.67	1.6	V	
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.5	μA
l <sub>OZ</sub>	OFF-state output current		-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.5	μA
$\Delta I_{OFF}$	additional power-off leakage current		-	-	±0.6	μΑ
I <sub>CC</sub>	supply current		-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; [1] $V_{CC} = 3.3 \text{ V}$	-	-	50	μΑ
		$\overline{\text{NOE}}$ input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; [1] V <sub>CC</sub> = 3.3 V	-	-	120	μΑ
		all inputs; $V_1$ = GND to 3.6 V; [2] $n\overline{OE}$ = GND; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	0 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
$I_{O} = -1.7 \text{ I}$ $I_{O} = -1.9 \text{ I}$ $I_{O} = -2.3 \text{ I}$ $I_{O} = -3.1 \text{ I}$ $I_{O} = -2.7 \text{ I}$ $I_{O} = -4.0 \text{ I}$		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
	I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V	
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.77	V V - 0.25 × V <sub>CC</sub> V - 0.30 × V <sub>CC</sub> V - 0.7 V - 0.9 V - 0.9 V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V V 0.36 V 0.50 V 0.50 V - ±0.75 µ - ±0.75 µ - ±0.75 µ - ±0.75 µ - 1.4 µ	V	
		$I_O = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.67	V			
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μA
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
ΔI <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; [1] $V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ
		$\overline{\text{NOE}}$ input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; [1] V <sub>CC</sub> = 3.3 V	-	-	180	μΑ
		all inputs; $V_I$ = GND to 3.6 V; [2] $n\overline{OE}$ = GND; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1	μA

Low-power dual buffer/line driver; 3-state

# 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions		25 °C		T <sub>an</sub>	<sub>nb</sub> = o +85 °C	T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
$C_L = 5 p$	F									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7. [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	20.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.2	4.8	1.7	6.1	1.7	6.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 8. [3]								
		V <sub>CC</sub> = 0.8 V	-	69.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.1	6.1	11.8	2.9	13.9	2.9	15.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	4.2	6.6	2.3	7.7	2.3	8.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	3.4	5.1	2.0	6.2	2.0	6.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	2.6	3.7	1.7	4.5	1.7	5.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.4	3.1	1.7	3.5	1.7	3.9	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 8. [4]								
		V <sub>CC</sub> = 0.8 V	-	14.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.7	4.3	6.5	2.7	7.3	2.7	8.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	3.2	4.4	2.1	5.1	2.1	5.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.0	4.3	2.0	5.0	2.0	5.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.2	2.9	1.4	3.3	1.4	4.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.5	3.2	1.7	3.4	1.7	3.9	ns

Symbol	Parameter	Conditions		25 °C		T <sub>an</sub>	<sub>nb</sub> = o +85 °C	T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7. [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	24.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 8. [3]								
		V <sub>CC</sub> = 0.8 V	-	73.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	6.9	13.5	3.4	15.8	3.4	17.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.8	7.7	2.2	8.6	2.2	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.9	5.8	1.9	6.8	1.9	7.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	3.2	4.3	1.7	5.3	1.7	5.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	3.0	3.9	1.7	4.3	1.7	4.8	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 8. [4]								
		V <sub>CC</sub> = 0.8 V	-	32.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.4	5.4	7.9	3.4	8.8	3.4	9.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.1	5.5	2.2	6.2	2.2	7.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.2	5.6	1.9	6.3	1.9	7.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.0	3.8	1.7	4.5	1.7	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	3.8	4.8	1.7	5.0	1.7	5.6	ns

Symbol	Parameter	er Conditions		25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 15	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7. [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	27.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 8. [3]								
		V <sub>CC</sub> = 0.8 V	-	77.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.0	7.7	15.2	3.7	17.6	3.7	19.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.3	8.4	2.5	9.8	2.5	10.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.4	6.5	2.1	7.7	2.1	8.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.6	5.0	2.0	6.1	2.0	6.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	4.4	1.9	4.9	1.9	5.5	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 8. [4]								
		V <sub>CC</sub> = 0.8 V	-	60.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	6.5	9.2	3.7	10.3	3.7	11.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.0	6.5	2.5	7.4	2.5	8.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.3	7.0	2.1	7.4	2.1	8.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.8	4.9	2.0	5.1	2.0	6.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.9	5.0	6.2	1.9	6.6	1.9	7.4	ns

### Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions	25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7. [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	37.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.8	9.5	19.0	4.4	21.6	4.4	24.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.5	2.5	8.3	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 8. [3]								
		V <sub>CC</sub> = 0.8 V	-	88.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	5.2	9.9	19.8	4.8	22.8	4.8	25.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.8	10.8	3.1	12.6	3.1	14.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.6	8.5	2.8	10.2	2.8	11.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.8	6.5	2.6	7.8	2.6	8.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.7	4.6	6.0	2.6	6.9	2.6	7.7	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 8. [4]								
		V <sub>CC</sub> = 0.8 V	-	49.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	6.0	9.9	13.3	4.8	14.8	4.8	16.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.4	7.7	9.6	3.1	10.8	3.1	12.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	5.1	8.7	11.1	2.8	12.4	2.8	13.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.6	6.2	7.6	2.6	8.6	2.6	9.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.2	8.7	10.5	2.6	10.8	2.6	13.1	ns
C <sub>L</sub> = 5 p	F, 10 pF, 15 p	F and 30 pF						,		•
C <sub>PD</sub>	power dissipation	output enabled; f <sub>i</sub> = 1 MHz; [5] V <sub>I</sub> = GND to V <sub>CC</sub>								
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF
	*								*	

- [1] All typical values are measured at nominal  $V_{CC}$ .
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . [2]
- t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.
- ten is the same as t<sub>PZD</sub> and t<sub>PZD</sub>.
   t<sub>dis</sub> is the same as t<sub>PHZ</sub> and t<sub>PLZ</sub>.
   C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

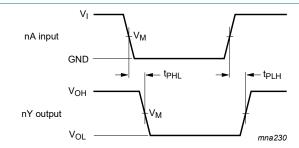
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

Low-power dual buffer/line driver; 3-state

#### 11.1. Waveforms and test circuit



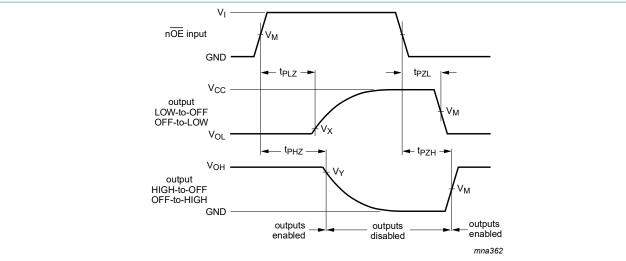
Measurement points are given in Table 9.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 7. The data input (nA) to output (nY) propagation delays

**Table 9. Measurement points** 

Supply voltage	Input			Output
V <sub>CC</sub>	V <sub>M</sub>	VI	$t_r = t_f$	V <sub>M</sub>
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>



Measurement points are given in <u>Table 10</u>.

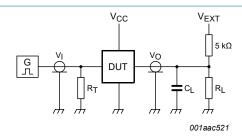
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 8. Enable and disable times

**Table 10. Measurement points** 

Supply voltage	Input	Output	Output				
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>			
0.8 V to 1.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> - 0.1 V			
1.65 V to 2.7 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V			
3.0 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V			

#### Low-power dual buffer/line driver; 3-state



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_O$  of the pulse generator;

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

#### Fig. 9. Test circuit for measuring switching times

#### Table 11. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

Low-power dual buffer/line driver; 3-state

# 12. Package outline

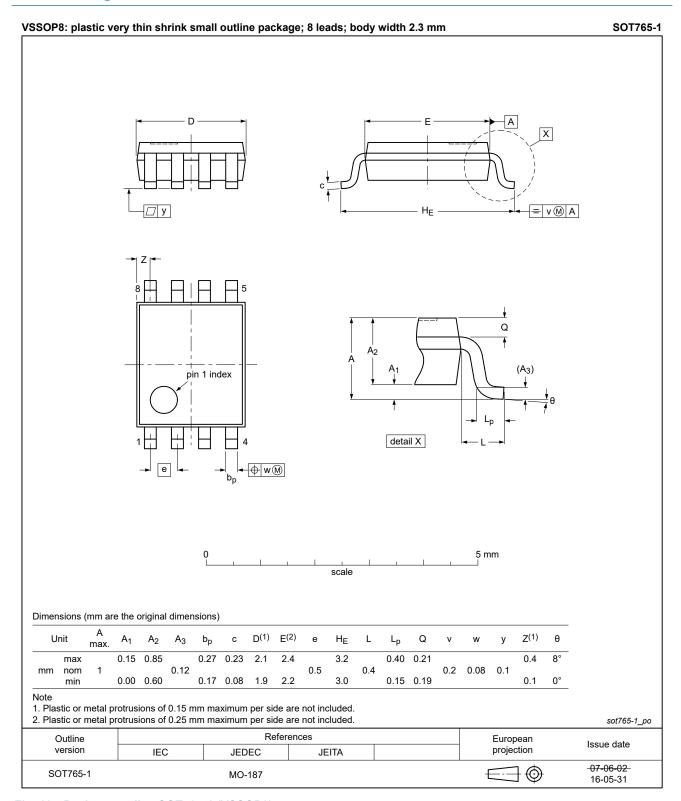


Fig. 10. Package outline SOT765-1 (VSSOP8)

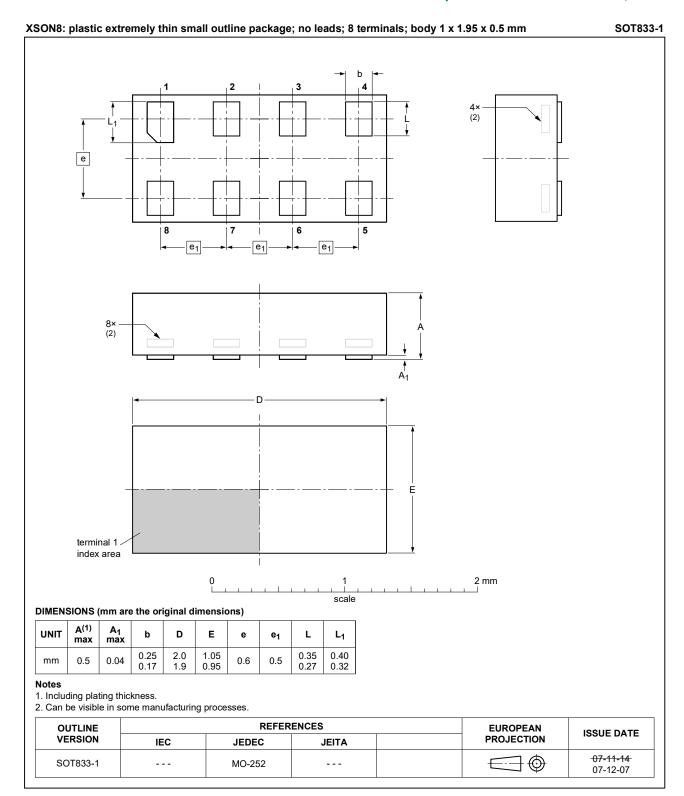


Fig. 11. Package outline SOT833-1 (XSON8)

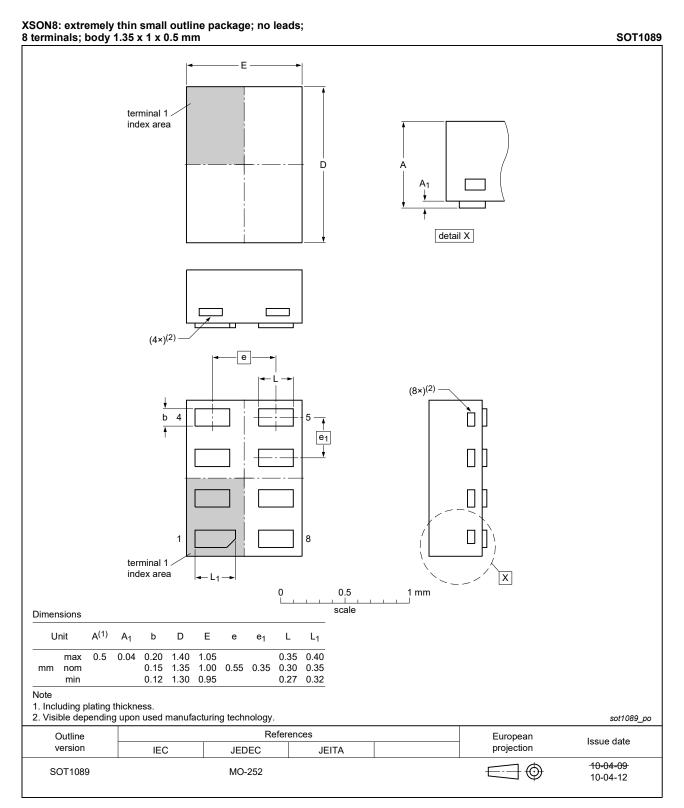


Fig. 12. Package outline SOT1089 (XSON8)

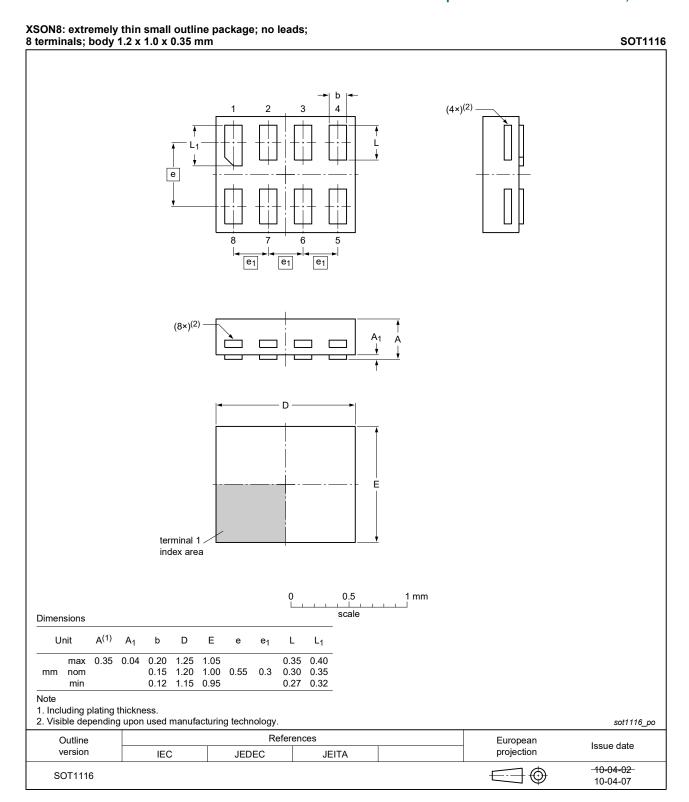


Fig. 13. Package outline SOT1116 (XSON8)

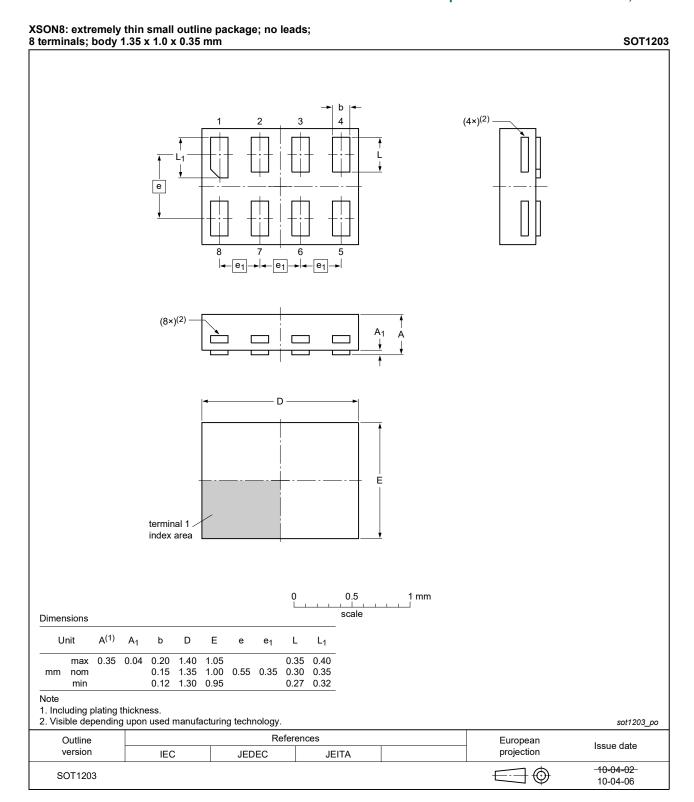


Fig. 14. Package outline SOT1203 (XSON8)

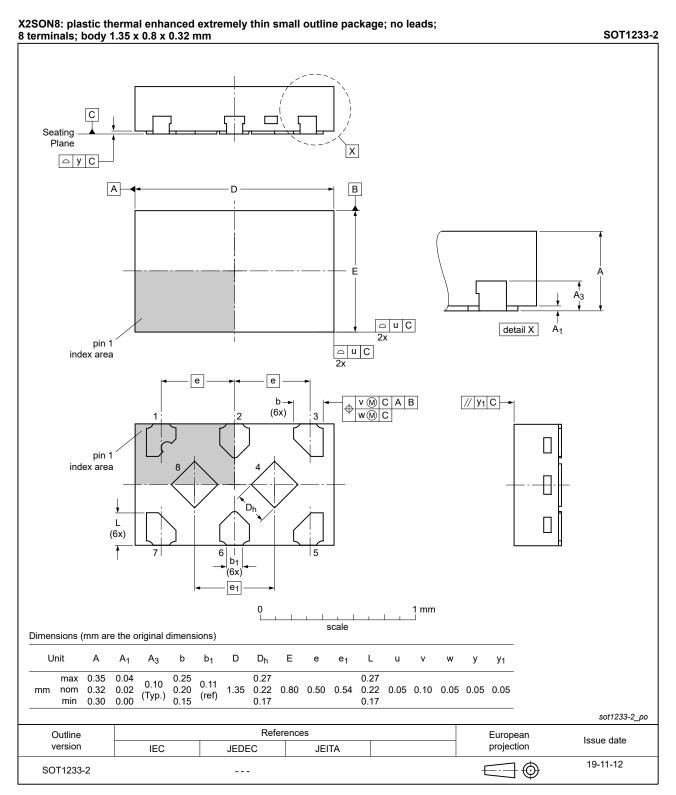


Fig. 15. Package outline SOT1233-2 (X2SON8)

Low-power dual buffer/line driver; 3-state

## 13. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

#### **Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G125 v.14	20220621	Product data sheet	-	74AUP2G125 v.13
Modifications:	Package SO	T1233 (X2SON8) chanç	ged to SOT1233-2 (2	X2SON8).
74AUP2G125 v.13	20220310	Product data sheet	-	74AUP2G125 v.12
Modifications:	• <u>Section 1</u> and	74AUP2G125GM (SOd Section 2 updated.	,	
74AUP2G125 v.12	20170703	Product data sheet	-	74AUP2G125 v.11
Modifications:	of Nexperia. • Legal texts h • <u>Fig. 6</u> and <u>Fig. 6</u>	f this data sheet has be ave been adapted to the g. 15 (drawings SOT12: 74AUP2G125GD remo	e new company nan 33/X2SON8) update	
74AUP2G125 v.11	20161028	Product data sheet	-	74AUP2G125 v.10
Modifications:	Added type r	number 74AUP2G125G	X (SOT1233/X2SON	N8)
74AUP2G125 v.10	20130208	Product data sheet	-	74AUP2G125 v.9
Modifications:	For type num	ber 74AUP2G125GD X	(SON8U has change	ed to XSON8.
74AUP2G125 v.9	20120607	Product data sheet	-	74AUP2G125 v.8
74AUP2G125 v.8	20111202	Product data sheet	-	74AUP2G125 v.7
74AUP2G125 v.7	20100921	Product data sheet	-	74AUP2G125 v.6
74AUP2G125 v.6	20091127	Product data sheet	-	74AUP2G125 v.5
74AUP2G125 v.5	20090202	Product data sheet	-	74AUP2G125 v.4
74AUP2G125 v.4	20090122	Product data sheet	-	74AUP2G125 v.3
74AUP2G125 v.3	20080409	Product data sheet	-	74AUP2G125 v.2
74AUP2G125 v.2	20070419	Product data sheet	-	74AUP2G125 v.1
74AUP2G125 v.1	20061017	Product data sheet	-	-

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## 15. Legal information

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Document status [1][2]	Product status [3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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